onsemi

0.9 V, Rail-to-Rail, Single Operational Amplifier NCS2001, NCV2001

The NCS2001 is an industry first sub-one voltage operational amplifier that features a rail-to-rail common mode input voltage range, along with rail-to-rail output drive capability. This amplifier is guaranteed to be fully operational down to 0.9 V, providing an ideal solution for powering applications from a single cell Nickel Cadmium (NiCd) or Nickel Metal Hydride (NiMH) battery. Additional features include no output phase reversal with overdriven inputs, trimmed input offset voltage of 0.5 mV, extremely low input bias current of 40 pA, and a unity gain bandwidth of 1.4 MHz at 5.0 V. The tiny NCS2001 is the ideal solution for small portable electronic applications and is available in the space saving SOT23–5 and SC70–5 packages with two industry standard pinouts.

Features

- 0.9 V Guaranteed Operation
- Rail-to-Rail Common Mode Input Voltage Range
- Rail-to-Rail Output Drive Capability
- No Output Phase Reversal for Over-Driven Input Signals
- 0.5 mV Trimmed Input Offset
- 10 pA Input Bias Current
- 1.4 MHz Unity Gain Bandwidth at ± 2.5 V, 1.1 MHz at ± 0.5 V
- Tiny SC70-5 and SOT23-5 Packages
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Single Cell NiCd/NiMH Battery Powered Applications
- Cellular Telephones
- Pagers
- Personal Digital Assistants
- Electronic Games
- Digital Cameras
- Camcorders
- Hand-Held Instruments



This device contains 63 active transistors. Figure 1. Typical Application





PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering, marking and shipping information in the dimensions section on page 14 of this data sheet.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage (V _{CC} to V _{EE})	V _S	7.0	V
Input Differential Voltage Range (Note 1)	V _{IDR}	$V_{\mbox{\scriptsize EE}}$ –300 mV to 7.0 V	V
Input Common Mode Voltage Range (Note 1)	V _{ICR}	$V_{\mbox{\scriptsize EE}}$ –300 mV to 7.0 V	V
Output Short Circuit Duration (Note 2)	t _{Sc}	Indefinite	sec
Junction Temperature	TJ	150	°C
Power Dissipation and Thermal Characteristics SOT23–5 Package Thermal Resistance, Junction–to–Air Power Dissipation @ $T_A = 70^{\circ}C$ SC70–5 Package Thermal Resistance, Junction–to–Air Power Dissipation @ $T_A = 70^{\circ}C$	R _{θJA} PD R _{θJA} PD	235 340 280 286	°C/W mW °C/W mW
Operating Ambient Temperature Range NCS2001 NCV2001 (Note 3)	T _A	-40 to +105 -40 to +125	°C
Storage Temperature Range	T _{stg}	-65 to 150	°C
ESD Protection at any Pin Human Body Model (Note 4)	V _{ESD}	1500	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Either or both inputs should not exceed the range of V_{EE} –300 mV to V_{EE} +7.0 V.

2. Maximum package power dissipation limits must be observed to ensure that the maximum junction temperature is not exceeded.

 $T_{J} = T_{A} + (P_{D} R_{\theta JA}).$

3. NCV prefix is qualified for automotive usage.

4. ESD data available upon request.

DC ELECTRICAL CHARACTERISTICS

(V_{CC} = 2.5 V, V_{EE} = -2.5 V, V_{CM} = V_O = 0 V, R_L to GND, T_A = 25^{\circ}C unless otherwise noted.)

Characteristics	Symbol	Min	Тур	Max	Unit
Input Offset Voltage	V _{IO}				mV
$V_{CC} = 0.45 \text{ V}, V_{EE} = -0.45 \text{ V}$					
$T_A = 25^{\circ}C$		-6.0	0.5	6.0	
$T_A = 0^{\circ}C$ to $70^{\circ}C$		-8.5	-	8.5	
$T_A = -40^{\circ}C$ to $125^{\circ}C$		-9.5	-	9.5	
V _{CC} = 1.5 V, V _{EE} = -1.5 V					
$T_A = 25^{\circ}C$		-6.0	0.5	6.0	
$T_A = 0^{\circ}C$ to $70^{\circ}C$		-7.0	-	7.0	
$T_A = -40^{\circ}C$ to $125^{\circ}C$		-7.5	-	7.5	
$V_{CC} = 2.5 V, V_{EE} = -2.5 V$					
$T_A = 25^{\circ}C$		-6.0	0.5	6.0	
$T_A = 0^{\circ}C$ to $70^{\circ}C$		-7.5	-	7.5	
$T_A = -40^{\circ}C$ to $125^{\circ}C$		-7.5	-	7.5	
Input Offset Voltage Temperature Coefficient ($R_S = 50$) T _A = -40°C to 125°C	$\Delta V_{IO} / \Delta T$	-	8.0	-	μV/°C
$I_{A}^{2} = -40 \ \text{C} \ \text{to} \ 123 \ \text{C}$					
Input Bias Current (V _{CC} = 1.0 V to 5.0 V)	I _{IB}	-	10	-	pА
Input Common Mode Voltage Range	V _{ICR}	-	V_{EE} to V_{CC}	-	V
Large Signal Voltage Gain	A _{VOL}				kV/V
$V_{CC} = 0.45 \text{ V}, V_{EE} = -0.45 \text{ V}$					
R _L = 10 k		-	40	-	
R _L = 2.0 k		-	20	-	
V _{CC} = 1.5 V, V _{EE} = -1.5 V					
R _L = 10 k		-	40	-	
R _L = 2.0 k		-	40	-	
V_{CC} = 2.5 V, V_{EE} = -2.5 V					
$R_L = 10 k$		20	40	-	
R _L = 2.0 k		15	40	-	

DC ELECTRICAL CHARACTERISTICS (continued) (V_{CC} = 2.5 V, V_{EE} = -2.5 V, V_{CM} = V_O = 0 V, R_L to GND, T_A = 25°C unless otherwise noted.)

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage Swing, High State Output (VID = +0.5 V)	V _{OH}				V
$V_{CC} = 0.45 \text{ V}, V_{EE} = -0.45 \text{ V}$					
$T_A = 25^{\circ}C$					
$R_L = 10 k$		0.40	0.494	-	
$R_{L} = 2.0 \text{ k}$		0.35	0.466	-	
T _A = 0°C to 70°C R _L = 10 k		0.40			
$R_{L} = 2.0 \text{ k}$		0.40	_	_	
$T_{A} = -40^{\circ}C$ to 125°C		0.00		_	
$R_L = 10 \text{ k}$		0.40	_	_	
$R_L = 2.0 \text{ k}$		0.35	-	-	
V _{CC} = 1.5 V, V _{EE} = -1.5 V					
$T_A = 25^{\circ}C$					
R _L = 10 k		1.45	1.498	-	
$R_{L} = 2.0 \text{ k}$		1.40	1.480	-	
$T_A = 0^{\circ}C$ to $70^{\circ}C$					
$R_L = 10 k$		1.45	-	-	
$R_{L} = 2.0 \text{ k}$		1.40	-	-	
$T_A = -40^\circ C$ to 125°C		1 45			
$R_L = 10 k$		1.45 1.40	-	-	
$R_L = 2.0 k$		1.40	-	_	
$V_{CC} = 2.5 \text{ V}, V_{EE} = -2.5 \text{ V}$ $T_A = 25^{\circ}\text{C}$					
$R_L = 10 \text{ k}$		2.45	2.498	_	
$R_{\rm I} = 2.0 \rm k$		2.40	2.475	_	
$T_A = 0^{\circ}C$ to 70°C					
$R_L = 10 \text{ k}$		2.45	-	-	
$R_{L} = 2.0 \text{ k}$		2.40	-	-	
$T_A = -40^{\circ}C$ to 125°C					
R _L = 10 k		2.45	-	-	
$R_L = 2.0 k$		2.40	-	-	
Output Voltage Swing, Low State Output (V _{ID} = -0.5 V)	V _{OL}				V
$V_{CC} = 0.45 \text{ V}, V_{EE} = -0.45 \text{ V}$	02				
$T_A = 25^{\circ}C$					
R _L = 10 k		-	-0.494	-0.40	
$R_L = 2.0 \text{ k}$		-	-0.480	-0.35	
$T_A = 0^{\circ}C$ to $70^{\circ}C$					
$R_L = 10 k$		-	-	-0.40	
$R_{L} = 2.0 \text{ k}$		-	-	-0.35	
$T_A = -40^{\circ}C$ to 125°C				0.40	
R _L = 10 k R _L = 2.0 k		_	-	-0.40 -0.35	
$V_{CC} = 1.5 \text{ V}, V_{EE} = -1.5 \text{ V}$		_	_	-0.00	
$T_A = 25^{\circ}C$					
$R_L = 10 \text{ k}$			1 402	-1.45	
		-	-1.495		
nj = 2.0 K		-	-1.493 -1.480	-1.40	
$R_{L} = 2.0 \text{ k}$ $T_{A} = 0^{\circ}\text{C to } 70^{\circ}\text{C}$		-			
$T_{A} = 0^{\circ}C \text{ to } 70^{\circ}C$ $R_{L} = 10 \text{ k}$		-		-1.40 -1.45	
$T_A = 0^{\circ}C \text{ to } 70^{\circ}C$ $R_L = 10 \text{ k}$ $R_L = 2.0 \text{ k}$		- - -		-1.40	
				-1.40 -1.45 -1.40	
$ \begin{array}{l} T_{A} = 0^{\circ}C \ to \ 70^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \\ T_{A} = -40^{\circ}C \ to \ 125^{\circ}C \\ R_{L} = 10 \ k \end{array} $		- -		-1.40 -1.45 -1.40 -1.45	
$\begin{array}{l} T_{A} = 0^{\circ}C \ to \ 70^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \\ T_{A} = -40^{\circ}C \ to \ 125^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \end{array}$			-1.480 - -	-1.40 -1.45 -1.40	
$\begin{array}{l} T_{A} = 0^{\circ}C \ to \ 70^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \\ T_{A} = -40^{\circ}C \ to \ 125^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \\ V_{CC} = 2.5 \ V, \ V_{EE} = -2.5 \ V \end{array}$		- -	-1.480 - -	-1.40 -1.45 -1.40 -1.45	
$\begin{array}{l} T_{A} = 0^{\circ}C \ to \ 70^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \\ T_{A} = -40^{\circ}C \ to \ 125^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \\ V_{CC} = 2.5 \ V, \ V_{EE} = -2.5 \ V \\ T_{A} = 25^{\circ}C \end{array}$			-1.480 - - - -	-1.40 -1.45 -1.40 -1.45 -1.40	
$\begin{array}{l} T_{A} = 0^{\circ}C \ to \ 70^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \\ T_{A} = -40^{\circ}C \ to \ 125^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \\ V_{CC} = 2.5 \ V, \ V_{EE} = -2.5 \ V \\ T_{A} = 25^{\circ}C \\ R_{L} = 10 \ k \end{array}$		- -	-1.480 - - - - -2.492	-1.40 -1.45 -1.40 -1.45 -1.40 -2.45	
$\begin{array}{l} T_{A} = 0^{\circ}C \ to \ 70^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \\ T_{A} = -40^{\circ}C \ to \ 125^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \\ \end{array}$			-1.480 - - - -	-1.40 -1.45 -1.40 -1.45 -1.40	
$\begin{split} T_A &= 0^\circ C \ to \ 70^\circ C \\ R_L &= 10 \ k \\ R_L &= 2.0 \ k \\ T_A &= -40^\circ C \ to \ 125^\circ C \\ R_L &= 10 \ k \\ R_L &= 2.0 \ k \\ V_{CC} &= 2.5 \ V, \ V_{EE} &= -2.5 \ V \\ T_A &= 25^\circ C \\ R_L &= 10 \ k \\ R_L &= 10 \ k \\ R_L &= 2.0 \ k \\ T_A &= 0^\circ C \ to \ 70^\circ C \end{split}$			-1.480 - - - - -2.492	-1.40 -1.45 -1.40 -1.45 -1.40 -2.45 -2.40	
$\begin{array}{l} T_{A} = 0^{\circ}C \ to \ 70^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \\ T_{A} = -40^{\circ}C \ to \ 125^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \\ V_{CC} = 2.5 \ V, \ V_{EE} = -2.5 \ V \\ T_{A} = 25^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \\ T_{A} = 0^{\circ}C \ to \ 70^{\circ}C \\ R_{L} = 10 \ k \end{array}$			-1.480 - - - - -2.492	-1.40 -1.45 -1.40 -1.45 -1.40 -2.45 -2.40 -2.45	
$\begin{array}{l} T_{A} = 0^{\circ}C \ to \ 70^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \\ T_{A} = -40^{\circ}C \ to \ 125^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \\ \end{array}$ $\begin{array}{l} V_{CC} = 2.5 \ V, \ V_{EE} = -2.5 \ V \\ T_{A} = 25^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \\ \end{array}$ $\begin{array}{l} T_{A} = 0^{\circ}C \ to \ 70^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \\ \end{array}$			-1.480 - - - - -2.492	-1.40 -1.45 -1.40 -1.45 -1.40 -2.45 -2.40	
$\begin{array}{l} T_{A} = 0^{\circ}C \ to \ 70^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \\ T_{A} = -40^{\circ}C \ to \ 125^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \\ V_{CC} = 2.5 \ V, \ V_{EE} = -2.5 \ V \\ T_{A} = 25^{\circ}C \\ R_{L} = 10 \ k \\ R_{L} = 2.0 \ k \\ T_{A} = 0^{\circ}C \ to \ 70^{\circ}C \\ R_{L} = 10 \ k \end{array}$			-1.480 - - - - -2.492	-1.40 -1.45 -1.40 -1.45 -1.40 -2.45 -2.40 -2.45	

DC ELECTRICAL CHARACTERISTICS (continued)

(V_{CC} = 2.5 V, V_{EE} = -2.5 V, V_{CM} = V_O = 0 V, R_L to GND, T_A = 25°C unless otherwise noted.)

Characteristics	Symbol	Min	Тур	Max	Unit
Common Mode Rejection Ratio (V _{in} = 0 to 5.0 V)	CMRR	60	70	-	dB
Power Supply Rejection Ratio (V_{CC} = 0.5 V to 2.5 V, V_{EE} = -2.5 V)	PSRR	55	65	-	dB
Output Short Circuit Current	I _{SC}				mA
V_{CC} = 0.45 V, V_{EE} = –0.45 V, V_{ID} = \pm 0.4 V					
Source Current High Output State		0.5	1.2	-	
Sink Current Low Output State		-	-3.0	-1.5	
V_{CC} = 1.5 V, V_{EE} = -1.5 V, V_{ID} = ±0.5 V		. –			
Source Current High Output State		15	29	-	
Sink Current Low Output State		-	-40	-20	
$V_{CC} = 2.5 \text{ V}, V_{EE} = -2.5 \text{ V}, V_{ID} = \pm 0.5 \text{ V}$		10			
Source Current High Output State		40	76	-	
Sink Current Low Output State		-	-96	-50	
Power Supply Current (Per Amplifier, V _O = 0 V)	I _D				mA
$V_{CC} = 0.45 \text{ V}, V_{EE} = -0.45 \text{ V}$	-				
$T_A = 25^{\circ}C$		-	0.51	1.10	
$T_A = 0^{\circ}C$ to $70^{\circ}C$		-	-	1.10	
$T_A = -40^{\circ}C$ to $125^{\circ}C$		-	-	1.10	
V _{CC} = 1.5 V, V _{EE} = -1.5 V					
$T_A = 25^{\circ}C$		-	0.72	1.40	
$T_A = 0^{\circ}C$ to $70^{\circ}C$		-	-	1.40	
$T_A = -40^{\circ}C$ to $125^{\circ}C$		-	-	1.40	
V_{CC} = 2.5 V, V_{EE} = -2.5 V					
$T_A = 25^{\circ}C$		-	0.82	1.50	
$T_A = 0^{\circ}C$ to $70^{\circ}C$		-	-	1.50	
$T_A = -40^{\circ}C$ to $125^{\circ}C$		-	-	1.50	

AC ELECTRICAL CHARACTERISTICS

(V_{CC} = 2.5 V, V_{EE} = –2.5 V, V_{CM} = V_{O} = 0 V, RL to GND, TA = 25°C unless otherwise noted.)

Characteristics	Symbol	Min	Тур	Max	Unit
Differential Input Resistance (V _{CM} = 0 V)	R _{in}	-	>1.0	-	tera Ω
Differential Input Capacitance (V _{CM} = 0 V)	C _{in}	-	3.0	-	pF
Equivalent Input Noise Voltage (f = 1.0 kHz)	e _n	-	100	-	nV/√Hz
Gain Bandwidth Product (f = 100 kHz) $V_{CC} = 0.45 V$, $V_{EE} = -0.45 V$ $V_{CC} = 1.5 V$, $V_{EE} = -1.5 V$ $V_{CC} = 2.5 V$, $V_{EE} = -2.5 V$	GBW	_ _ 0.5	1.1 1.3 1.4		MHz
Gain Margin (R_L = 10 k, C_L = 5.0 pf)	Am	-	6.5	-	dB
Phase Margin ($R_L = 10 \text{ k}, C_L = 5.0 \text{ pf}$)	φm	-	60	-	0
Power Bandwidth (V_O = 4.0 V_{pp}, R_L = 2.0 k, THD = 1.0%, A_V = 1.0)	BW _P	-	80	-	kHz
Total Harmonic Distortion (V _O = 4.0 V _{pp} , R _L = 2.0 k, A _V = 1.0) f = 1.0 kHz f = 10 kHz	THD		0.008 0.08	-	%
Slew Rate (V_S = ±2.5 V, V_O = -2.0 V to 2.0 V, R_L = 2.0 k, A_V = 1.0) Positive Slope Negative Slope	SR	1.0 1.0	1.6 1.6	6.0 6.0	V/μs













Figure 28. Input Offset Voltage vs. Common Mode Input Voltage Range, $V_S = \pm 0.45 V$

Figure 29. Common–Mode Input Voltage Range vs. Power Supply Voltage

APPLICATION INFORMATION AND OPERATING DESCRIPTION

GENERAL INFORMATION

The NCS2001 is an industry first rail-to-rail input, rail-to-rail output amplifier that features guaranteed sub-one voltage operation. This unique feature set is achieved with the use of a modified analog CMOS process that allows the implementation of depletion MOSFET devices. The amplifier has a 1.0 MHz gain bandwidth product, 2.2 V/ μ s slew rate and is operational over a power supply range less than 0.9 V to as high as 7.0 V.

Inputs

The input topology chosen for this device series is unconventional when compared to most low voltage operational amplifiers. It consists of an N–Channel depletion mode differential transistor pair that drives a folded cascade stage and current mirror. This configuration extends the input common mode voltage range to encompass the V_{EE} and V_{CC} power supply rails, even when powered from a combined total of less than 0.9 V. Figures 27 and 28 show the input common mode voltage range versus power supply voltage.

The differential input stage is laser trimmed in order to minimize offset voltage. The N–Channel depletion mode MOSFET input stage exhibits an extremely low input bias current of less than 10 pA. The input bias current versus temperature is shown in Figure 4. Either one or both inputs can be biased as low as V_{EE} minus 300 mV to as high as 7.0 V without causing damage to the device. If the input common mode voltage range is exceeded, the output will not display a phase reversal. If the maximum input positive or negative voltage ratings are to be exceeded, a series resistor must be used to limit the input current to less than 2.0 mA.

The ultra low input bias current of the NCS2001 allows the use of extremely high value source and feedback resistor without reducing the amplifier's gain accuracy. These high value resistors, in conjunction with the device input and printed circuit board parasitic capacitances C_{in} , will add an additional pole to the single pole amplifier in Figure 30. If low enough in frequency, this additional pole can reduce the phase margin and significantly increase the output settling time. The effects of C_{in} , can be canceled by placing a zero into the feedback loop. This is accomplished with the addition of capacitor C_{fb} . An approximate value for C_{fb} can be calculated by:

$$C_{fb} = \frac{R_{in} \times C_{in}}{R_{fb}}$$



Cin = Input and printed circuit board capacitance

Figure 30. Input Capacitance Pole Cancellation

Output

The output stage consists of complementary P and N–Channel devices connected to provide rail–to–rail output drive. With a 2.0 k load, the output can swing within 50 mV of either rail. It is also capable of supplying over 75 mA when powered from 5.0 V and 1.0 mA when powered from 0.9 V.

When connected as a unity gain follower, the NCS2001 can directly drive capacitive loads in excess of 820 pF at room temperature without oscillating but with significantly reduced phase margin. The unity gain follower configuration exhibits the highest bandwidth and is most prone to oscillations when driving a high value capacitive load. The capacitive load in combination with the amplifier's output impedance, creates a phase lag that can result in an under-damped pulse response or a continuous oscillation. Figure 32 shows the effect of driving a large capacitive load in a voltage follower type of setup. When driving capacitive loads exceeding 820 pF, it is recommended to place a low value isolation resistor between the output of the op amp and the load, as shown in Figure 31. The series resistor isolates the capacitive load from the output and enhances the phase margin. Refer to Figure 33. Larger values of R will result in a cleaner output waveform but excessively large values will degrade the large signal rise and fall time and reduce the output amplitude. Depending upon the capacitor characteristics, the isolation resistor value will typically be between 50 to 500 Ω . The output drive capability for resistive and capacitive loads is shown in Figures 2, 3, and 23.



Isolation resistor R = 50 to 500

Figure 31. Capacitance Load Isolation

Note that the lowest phase margin is observed at cold temperature and low supply voltage.



Figure 32. Small Signal Transient Response with Large Capacitive Load









The non–inverting input threshold levels are set so that the capacitor voltage oscillates between 1/3 and 2/3 of V_{CC} . This requires the resistors $R_{1a},\,R_{1b}$ and R_2 to be of equal value. The following formula can be used to approximate the output frequency.

$$f_{O} = \frac{1}{1.39 \ R_{T}C_{T}}$$





















I _s	vo
435 mA	34.7 mV
212 mA	36.9 mV

For best performance, use low tolerance resistors.

Figure 39. High Side Current Sense

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NCS2001SN1T1G	AAG		
NCS2001SN2T1G	AAH	SOT23–5 (Pb–Free)	
NCV2001SN2T1G*	MBB	(* = * * = =)	3000 / Tape & 7" Reel
NCS2001SQ2T2G	AAJ	SC70-5	
NCV2001SQ2T2G*	AAJ	(Pb-Free)	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

NSEM



SC-88A (SC-70-5/SOT-353) CASE 419A-02 **ISSUE M**

NDTES: 1.

2.

З.

DATE 11 APR 2023











RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

DIM	MILLIMETERS				
MIU	MIN.		MAX.		
A	0.80	0.95	1.10		
A1			0.10		
A3	0.20 REF				
b	0.10	0.20	0.30		
С	0.10		0.25		
D	1.80	2.00	5'50		
E	2.00	2.10	5'50		
E1	1.15	1.25	1.35		
e		0.65 BSI	С		
L	0.10	0.30			

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,

PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS,

OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

CONTROLLING DIMENSION: MILLIMETERS 419A-01 DBSOLETE, NEW STANDARD 419A-02

GENERIC MARKING





*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

Μ = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

STYLE 1: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR 5. CATHODE	STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1	STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1 5. GATE 2	STYLE 5: PIN 1. CATHODE 2. COMMON ANOD 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4	E
STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE	STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 1 5. COLLECTOR	STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	Note: Please refer to style callout. If style to out in the datasheet r datasheet pinout or p	ype is not called efer to the device
DOCUMENT NUMBER:	98ASB42984B			ot when accessed directly from when stamped "CONTROLLED (
DESCRIPTION:	SC-88A (SC-70-	5/SOT-353)			PAGE 1 OF 1

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

TSOP-5 3.00x1.50x0.95, 0.95P **CASE 483** ISSUE P DATE 01 APR 2024 NOTES: 5X b 0.20 C A B DIMENSIONING AND TOLERANCING CONFORM TO ASME NOTE 5 1. Y14.5-2018. ALL DIMENSION ARE IN MILLIMETERS (ANGLES IN DEGREES). MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. 2. В 3. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL. Ė1 4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OF GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION D. 5 OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS PIN 1 ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND IDENTIFIER le MORE THAN 0.2 FROM BODY. A MILLIMETERS DIM NOM. TOP VIEW MIN. MAX 0.900 1.000 1.100 DETAIL A А (A2) A1 0.010 0.055 0.100 Α2 0.950 REF 0.250 0.375 0.500 h 0.100 0.180 0.260 С 0.05 C SEATING 2.850 D 3.000 3.150 Ċ A1 PLANE END VIEW SIDE VIEW Ε 2.500 2.750 3.000 1.350 E1 1.500 1.650 0.950 BSC е 0.250 GAUGE 0.400 L 0.200 0.600 0° 5° 10° Θ 1.900Ð 0.950 "A DETAIL SCALE 2:1 GENERIC **MARKING DIAGRAM*** 2.400 5 5 XXXAYW= XXX M= 1.000 1 0.700Analog Discrete/Logic RECOMMENDED MOUNTING FOOTPRINT* XXX = Specific Device Code XXX = Specific Device Code FOR ADDITIONAL INFORMATION ON OUR Pb-FREE А = Assembly Location Μ = Date Code STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD = Pb-Free Package v = Year THE ON SEMICONDUCTOR SOLDERING AND MOUNTING W = Work Week TECHNIQUES REFERENCE MANUAL, SOLDERRM/D. = Pb-Free Package (Note: Microdot may be in either location) *This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking. Electronic versions are uncontrolled except when accessed directly from the Document Repository. DOCUMENT NUMBER: 98ARB18753C Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. **DESCRIPTION:** TSOP-5 3.00x1.50x0.95, 0.95P PAGE 1 OF 1 onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

DUSEU

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent_Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>